



APTM120H29FG Information



For Reference Only

Part Number APTM120H29FG
Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET 4N-CH 1200V 34A SP6

Package SP6

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APTM120H29FG Specifications

	Report errors?
Supplier Device Package	SP6
Package / Case	SP6
Mounting Type	Chassis Mount
Operating Temperature	-40°C ~ 150°C (TJ)
Power - Max	780W
Input Capacitance (Ciss) (Max) @ Vds	10300pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	374nC @ 10V
Vgs(th) (Max) @ Id	5V @ 5mA
Rds On (Max) @ Id, Vgs	348 mOhm @ 17A, 10V
Current - Continuous Drain (Id) @ 25°C	34A
Drain to Source Voltage (Vdss)	1200V (1.2kV)
FET Feature	Standard
FET Type	4 N-Channel (H-Bridge)
Series	POWER MOS 7?
Package	SP6
	Transistors - FETs, MOSFETs - Arrays
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Manufacturer Part Number	APTM120H29FG

APTM120H29FG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM120H29FG Payment Methods



















APTM120H29FG Shipping Methods













If you have any question about APTM120H29FG, please do not hesitate to contact us!

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